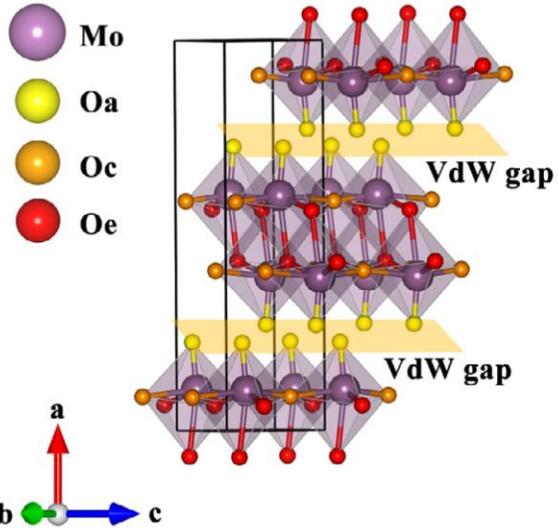
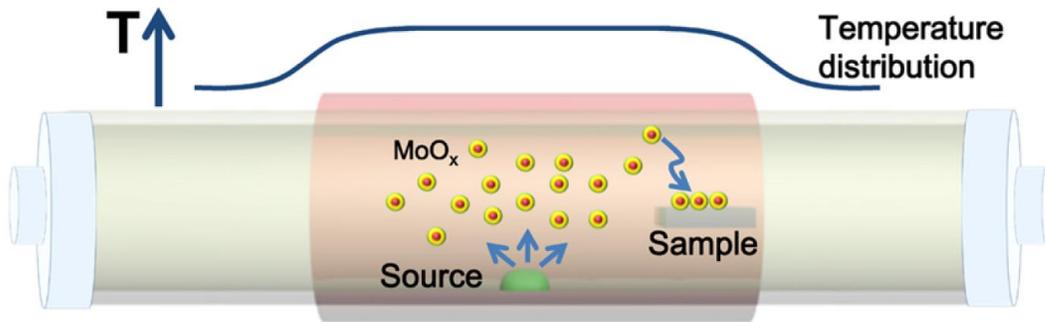


# Growth of Well-Oriented MoO<sub>3</sub> Crystal



MoO<sub>3</sub> is a n-type wide band-gap semiconductor with gap about 3 eV.  
 2D nanosheets of MoO<sub>3</sub> and their heterostructures show great potential for various application.



Thermal physical deposition



[Lidong.sun@jku.at](mailto:Lidong.sun@jku.at)  
 Office: P116